

Peak gate current ($t_p=20 \text{ s}$, $T_j=125 \text{ }^\circ\text{C}$)

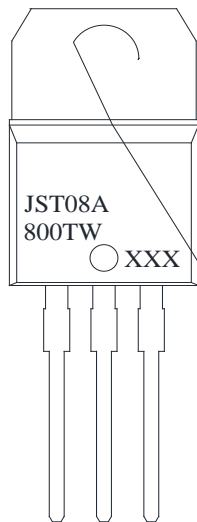
I_{GM}

4

ORDERING INFORMATION

J	ST	08	A	-800	TW
JieJie Microelectronics Co., Ltd.	Triacs	$I_{T(RMS)}:8A$	A:TO-220A(Ins)	800:V _{DRM} /V _{RRM} 1800V	TW:IGT1-3 05mA

MARKING



JST08A-800TW

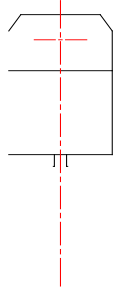


Jie Jie Microelectronics Co., Ltd.

A' AT 6@0DdXEPEPD, QEP@E' E€EPD D€

v6W-79-0.0 0 Tw (.)Tlj 0J /43 (-5 (-0.0 Tc4-0.002 Tw 12 0 321d [(5)-13.10 (s)44.2 onian)10 (d

RG enAR Load MoRA' LADq`!Đ °RGAd



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